SCAS025C - JULY 1987 - REVISED APRIL 1996

- Compares Two 8-Bit Words
- Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Equivalent of 20-kΩ Pullup Resistor on Q Inputs
- Package Options Include Plastic Small-Outline Packages (DW) and Standard Plastic 300-mil DIPs (N)

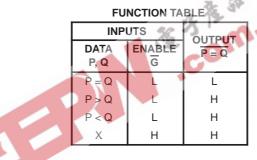
(TOP VIEW) 20 🛮 🗖 Q1 l P1 [] 19 P2 Q0 [3 18 Q2 P0 [17 P3 GND [16 Q3 15 V_{CC} $P = Q \cap G$ Q7 🛮 7 14 P4 P7 🛮 8 13 Q4 9 12 P5 Q6 L 11 Q5 P6 🛮 10

DW OR N PACKAGE

description

This identity comparator performs comparisons on two 8-bit binary or BCD words. Features include $20\text{-k}\Omega$ pullup termination resistors on the Q inputs for analog or switch data and a $\overline{P}=\overline{Q}$ totem-pole output.

The 74AC11520 is characterized for operation from -40°C to 85°C.





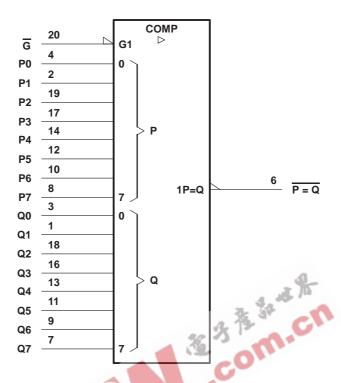
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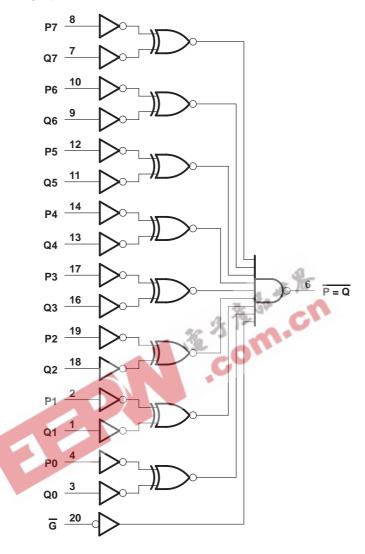
SCAS025C - JULY 1987 - REVISED APRIL 1996

logic symbol[†]

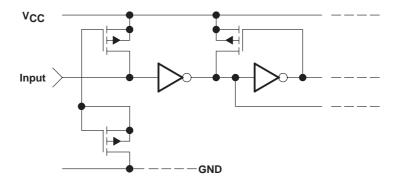


[†] This symbol is in accordance with ANSI/IEEE Std 91–1984 and IEC Publication 617–12.

logic diagram (positive logic)



schematic of Q inputs



SCAS025C - JULY 1987 - REVISED APRIL 1996

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	\dots -0.5 V to V _{CC} + 0.5 V
Output voltage range, V _O (see Note 1)	\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Maximum power dissipation at T _A = 55°C (in still air) (see Note 2): DW package	1.6 W
N package	1.3 W
Storage temperature range, T _{sto}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The maximum package power dissipation is calculated using a junction temperature of 150 °C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions

ecom	mended operating conditions	A A					
		7: 30	MIN	NOM	MAX	UNIT	
VCC	Supply voltage	20 x 72 0	3	5	5.5	V	
		V _{CC} = 3 V	2.1				
V_{IH}	High-level input voltage	$V_{CC} = 4.5 \text{ V}$	3.15			V	
		V _{CC} = 5.5 V	3.85				
	Low-level input voltage	V _{CC} = 3 V			0.9		
V_{IL}		V _{CC} = 4.5 V			1.35	V	
		V _{CC} = 5.5 V			1.65		
VI	Input voltage		0		VCC	V	
٧o	Output voltage		0		Vcc	V	
		VCC = 3 V			-4		
lOH	High-level output current	V _{CC} = 4.5 V			-24	mA	
		V _{CC} = 5.5 V			-24		
	Low-level output current	VCC = 3 V			12		
lOL		V _{CC} = 4.5 V			24	mA	
		V _{CC} = 5.5 V			24		
Δt/Δν	Input transition rise or fall rate	-	0		10	ns/V	
TA	Operating free-air temperature		-40		85	°C	

SCAS025C - JULY 1987 - REVISED APRIL 1996

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		vcc	T _A = 25°C			MIN	MAX	UNIT
PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	IVIIIV	IVIAA	UNIT
			3 V	2.9	2.9		2.9		
	I _{OH} = -50 μA		4.5 V	4.4			4.4		
			5.5 V	5.4			5.4		
Voн	I _{OH} = -4 mA		3 V	2.58			2.48		V
	Jan. 24 mA		4.5 V	3.94			3.8		
	I _{OH} = -24 mA		5.5 V	4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\dagger}$		5.5 V				3.85		
	I _{OL} = 50 μA		3 V			0.1		0.1	
			4.5 V			0.1		0.1	
			5.5 V			0.1		0.1	
V _{OL}	I _{OL} = 12 mA		3 V			0.36		0.44	V
	I _{OL} = 24 mA		4.5 V	-		0.36		0.44	
			5.5 V	2 15		0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$		5. 5 V	-				1.65	
lіН	$V_I = V_{CC}$	Q inputs only	5.5 V		100	10		10	μА
IIL	$V_I = GND,$	Q inputs only	5.5 V	12	-0.3	-0.6		-1	mA
lį	$V_I = V_{CC}$ or GND,	P and G inputs only	5.5 V			±0.1		±1	μΑ
la a	Q inputs at GND,	Other inputs V _I = V _{CC} or GND	5.5 V		2.3	4.8		8	mA
lcc	Q inputs open,	Other inputs V _I = V _{CC} or GND	5.5 V			8		80	μΑ
C _i	$V_I = V_{CC}$ or GND		5 V		3.5				pF

[†] Not more than one output or input should be tested at a time and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	T _A = 25°C			MIN	MAX	UNIT
PARAMETER	(INPUT)		MIN	TYP	MAX	IVIIIV	IVIAA	UNIT
t _{PLH}	P or Q		1.5	12	16.5	1.5	18.6	200
^t PHL		P = Q	1.5	10.4	14.4	1.5	16.3	ns
t _{PLH}	G	$\overline{P} = Q$	1.5	6.9	9	1.5	10	200
^t PHL	G	P = Q	1.5	6.3	8.6	1.5	9.5	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

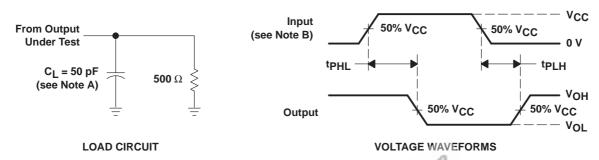
PARAMETER	FROM	то	T,	T _A = 25°C	MIN	N MAX	UNIT	
PARAMETER	(INPUT) (INPUT)	MIN	TYP	MAX	IVIIIV		ONIT	
tpLH	P or Q		1.5	8.1	11.1	1.5	12.6	no
t _{PHL}	POIQ	P = Q	1.5	7.1	10.1	1.5	11.3	ns
tpLH	<u>-</u>	<u>P = Q</u>	1.5	4.9	6.6	1.5	7.4	no
t _{PHL}	G	P=Q	1.5	4.8	7.1	1.5	7.8	ns

SCAS025C - JULY 1987 - REVISED APRIL 1996

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST COM	TYP	UNIT	
C _{pd}	Power dissipation capacitance	C _L = 50 pF,	f = 1 MHz	42	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_{O} = 50 Ω , t_{f} = 3 ns, t_{f} = 3 ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS Q INPUT CURRENT VS INPUT VOLTAGE O VCC = 5 V, TA = 25°C -50 -50 -50 TA = 25°C -300 0 1 2 3 4 5 6 V_I - Input Voltage - V

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Figure 2

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